GS358

Dual Operational Amplifiers

Product Description

The GS358 consists of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages.

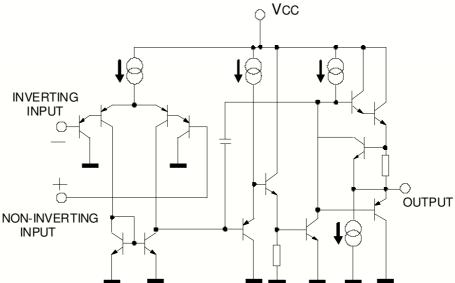
Operation from split power supplies is also possible and the low power supply current drains in independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, dc gain blocks and all the conventional op amp circuits, which now can be more easily implemented in single power supply systems. For example, the GS358 can be directly operated off of the standard +5V power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional ±15V power supplies.

Features

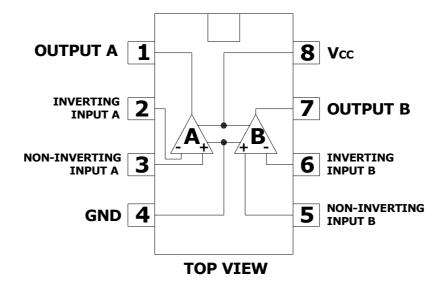
- Wide range of supply voltages 3V to 32V
- Low supply current drain independent of supply
- Supply Current 0.5mA (TYP.)
- Low input biasing current
- Low input offset voltage and offset current
- Input common-mode voltage range includes
- around
- Differential input voltage range equal to the
- power supply voltage
- DC voltage gain: 100V/mV TYP.
- Internally frequency compensation
- RoHS Compliant, 100%Pb & Halogen Free
- ESD Protection(2KV) between V+/V- and GND

Block Diagram

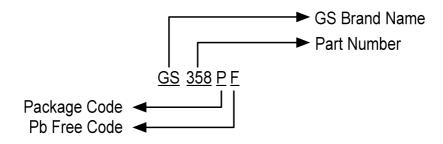




Pin Assignments



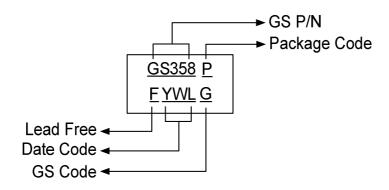
Ordering Information



Device	Package	Quantity Reel	
GS358SF	SOP-8	4000 PCS	

S.258

Marking Information



Absolute Maximum Ratings

Symbol	Parameter	Value		Unit
Vcc	Single Supply 36		i	V
V _{CC} , V _{EE}	Split Supply	±16	6	V
V _{IDR}	Input Differential Voltage Range ±32		V	
los	Output Short-circuit to GND		uous	
TJ	Junction Temperature 150		ōС	
T _{STG}	Storage Temperature Range	-65 to +150		ōC
TA	Operating Ambient Temperature Range -40 to 85		ōC	
Өја	Thermal Resistance (Junction to Ambient)	SOP-8	160	^o C/W
θις	θ _{JC} Thermal Resistance (Junction to Case)		22	^o C/W
ESD	ESD Rating (HBM)	2		ΚV



Electrical Characteristics

at specified free-air temperature, V_{CC} =5V (Unless Otherwise Noted)

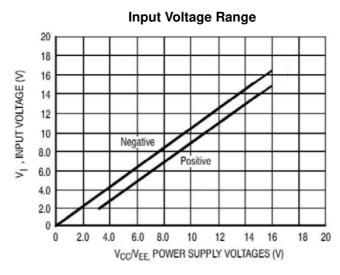
Symbol Parameter		Test Conditions*		Min	Тур	Max	Unit
	Input offset	Vcc=5V to Max.	25ºC		2	5	1
V _{IO}	voltage	$V_{IC}=V_{ICR}$ min, $V_{O}=1.4V$	Full range			7	mV
αV_{IO}	Average temperature coefficient of input offset voltage		Full range		7		μV/º(
lio	Input offset current	Vo = 1.4V	25ºC		2	50	nA
αl _{IO}	Average temperature coefficient of input offset current		Full range		10	150	p A /º(
, [lanut bigg gurrant	Vo = 1.4V	25ºC		20	250	4
I _{IB}	Input bias current	VO = 1.4V	Full range			500	nA
V _{ICR}	Common-mode input voltage	V _{CC} = 5V to MAX	25ºC	0 to Vcc-1.5			V
	ange		Full range	0 to Vcc-2			
V _{OH} High-level с voltage		$R_L = 2k\Omega$	25ºC	Vcc-1.5			v
	High-level output	$V_{CC} = MAX,$ $R_L = 2k\Omega$	Full range	26			
	voltage	$V_{CC} = MAX,$ $R_L = 10k\Omega$	Full range	27	28		
V _{OL}	Low-level output voltage	R _L = 10kΩ	Full range		5	20	mV
	Large-signal	$V_{CC} = 15V$ $V_{O} = 1V$ $V_{C} = 11V$ $V_{C} = 11V$ $V_{C} = 15V$	25ºC	25	100		V/mV
Avd	differential voltage amplification		Full range	15			
CMRR	Common-mode rejection ratio	$V_{CC} = 5V \text{ to MAX}$ $V_{IC} = V_{ICR} \text{ min}$	25ºC	65	80		dB
K _{SVR}	Supply voltage rejection ratio $(\Delta V_{CC}/\Delta V_{IO})$	V _{CC} = 5V to MAX	25ºC	65	100		dB
V _{O1} /V _{O2}	Crosstalk attenuation	f = 1k to 20k (Hz)	25ºC		120		dB
		V _{CC} = 15V, V _{ID} = 1V, V _O = 0V	25ºC	-20	-30		mA
lo Outpu			Full range	-10			
	Output current	Vcc = 15V	25ºC	10	20		
	Jaipai Garierii	V _{ID} = -1V, Vo = 15V	Full range	5			
		V _{ID} = -1V, Vo = 200mV	25ºC	12	30		μA
los	Short-circuit output current	V _{CC} at 5V, GND at –5V, Vo = 0V	25ºC		±40	±60	mA
		Vo =2.5V,No load	Full range		0.5	1.2	
Supply current (two amplifiers)		Vcc = MAX, Vo = 0.5Vcc, No load	Full range		1	2	mA

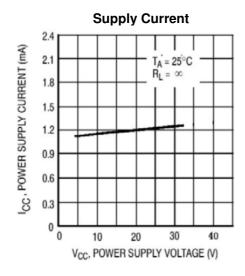
^{*}All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. "MAX" V_{CC} for testing Purposes is 30V. Full range is -40°C to 85°C

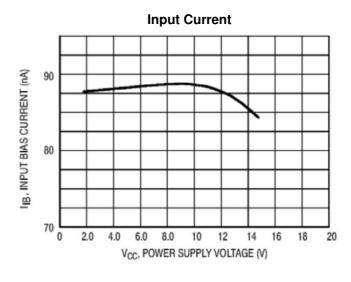


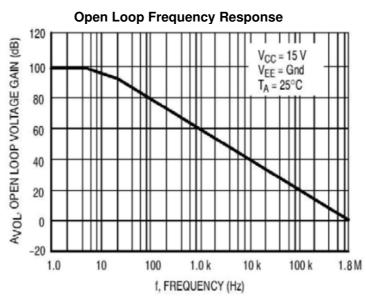
- 6535

Typical Performance Characteristics







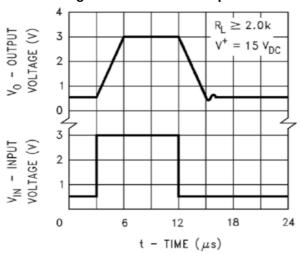




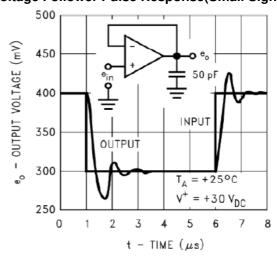
- GS35

Typical Performance Characteristics (Continue)

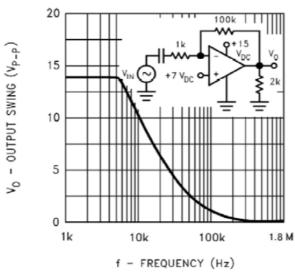
Voltage Follower Pulse Response



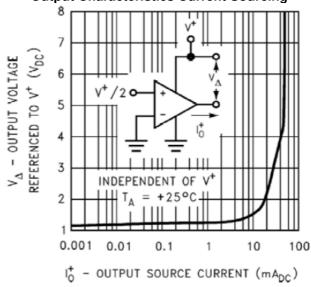
Voltage Follower Pulse Response(Small Signal)



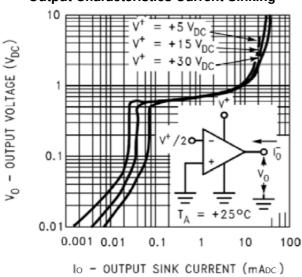
Large Signal Frequency Response



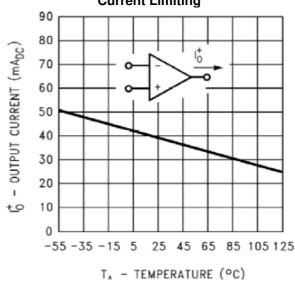
Output Characteristics Current Sourcing



Output Characteristics Current Sinking

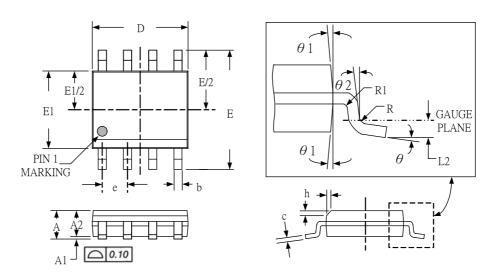


Current Limiting



Package Dimension

SOP-8 PLASTIC PACKAGE



		Dimensions			
OVMDOL	Millimeters		Inches		
SYMBOL	MIN	MAX	MIN	MAX	
Α	1.35	1.75	.053	.069	
A2	1.25	1.65	.049	.065	
b	0.31	0.51	.012	.020	
b1	0.28	0.48	.011	.019	
С	0.17	0.25	.007	.010	
A 1	0.1(MAX)		0.004(MAX)		
D	4.70	5.20	.185	.205	
E	5.80	6.20	.228	.244	
E1	3.70	4.10	.146	.161	
е	1.27 (TYP)		.050 (TYP)		
L	0.40	1.27	.016	.050	
L1	1.04 (TYP)		.041 (TYP)		
L2	0.25 (TYP)		.010 (TYP)		
R	0.07	-	.003	-	
R1	0.07	-	.003	-	
h	0.25	0.50	.010	.020	
θ	0°	8°	0°	8°	
θ1	5°	15°	5°	15°	
θ2	0°	-	0°	-	



NOTICE

Information furnished is believed to be accurate and reliable. However Globaltech Semiconductor assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties, which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Globaltech Semiconductor. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information without express written approval of Globaltech Semiconductor.

CONTACT US

GS Headquarter		
\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	4F.,No.43-1,Lane11,Sec.6,Minquan E.Rd Neihu District Taipei City 114, Taiwan (R.O.C)	
Çō	886-2-2657-9980	
	886-2-2657-3630	
@	sales_twn@gs-power.com	

RD Division				
	824 Bolton Drive Milpitas. CA. 95035			
F	1-408-457-0587			

